



**KT 90  
BEAM PENTRODE  
FOR AF POWER AMPLIFIER  
APPLICATIONS**

The KT-90 is a beam-power pentode primarily designed for use in audio frequency power amplifier applications. It carries a 50 watt anode dissipation rating which provides for push-pull amplifier utilization up to 110 watts output per pair with 550 volts on the anode. Up to 160 watts per pair may be derived with an anode voltage of 750 V and 600 V on the screen grid - well within the design centre maximum parameters.

The KT-90 is recommended as a replacement for the 6550, 6550A, and KT-88 with major benefits as to power output, vastly increased anode and screen grid maximum voltage, lower distortion, and cool running leading to greatly extended useful tube life.

**GENERAL**

**ELEKTRICAL**

Heater characteristics and ratings:

Heater voltage AC or DC                    6.3 ± 0.6 volts  
Heater current                                    1.6 amperes

Direct interelectrode capacitances:

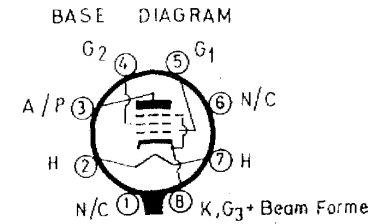
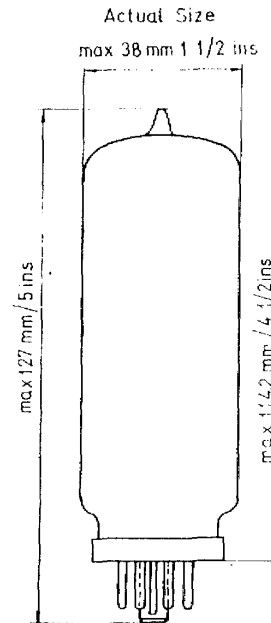
Grid - Number 1 anode                        1.8 pF  
Grid 1 to (H + K + g<sub>2</sub> + BA + A)            29 pF  
Anode to (H + K + g<sub>2</sub> + BA + g<sub>1</sub>)           10 pF

**MECHANICAL**

Mounting position - Any  
Envelope - Glass  
Base - Universal octal 8-pin

**TERMINAL CONNECTIONS**

- PIN 1 - No Connections
- PIN 2 - Heater
- PIN 3 - Anode
- PIN 4 - Grid number 2 (screen)
- PIN 5 - Grid number 1
- PIN 6 - No Connection
- PIN 7 - Heater
- PIN 8 - Cathode and Beam Forming tube



**MAXIMUM RATINGS (ABSOLUTE)**

	Pentode Connection	Triode Connection
Ua	750 V	600 V
Ug2	650 V	-
Ua Ug2	650 V	600 V
- Ug1	200 V	200 V
Pa (Dissipation)	50 W	50 W
Pg2	8 W	-
Pa + g2	54 W	-
Ik	230 mA	230 mA
Uk-f (total DC)	300 V	300 V

**CHARACTERISTICS**

**AS A GUIDE**

Average characteristics, pentode connection

Ua	250 V	400 V
Ug2	250 V	300 V
- Ug1	14 V	27 V
ia	145 mA	90 mA
Ig2	8 mA	4,7 mA
- Ug1 (ia = 1mA Approx)	36 V	42 V
gm	14 mA/V	8,8 mA/V
Ri (Approx)	11 Kohm	25 Kohm

**AVERAGE CHARACTERISTICS, TRIODE CONNECTION**

Ua, Ug2	250 V
- Ug1	14 V
ia + g2	153 mA
gm	15 mA/V
Ri (approx)	650 ohms
(amplification factor)	9

